NSN 5962-01-377-1141

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-377-1141 **Body Length:** 0.450 inches **Body Width:** 0.450 inches **Body Height:** 0.110 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+125.0 degrees celsius **End Application:** 5820-01-306-3838 receiver-transmitter, radio **Features Provided:** Electrostatic sensitive and w/buffered output and high impedance and 3-state output and w/clock and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Current Rating Per Characteristic:** 10.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.2 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds access **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 leadless Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

NSN 5962-01-377-1141

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0